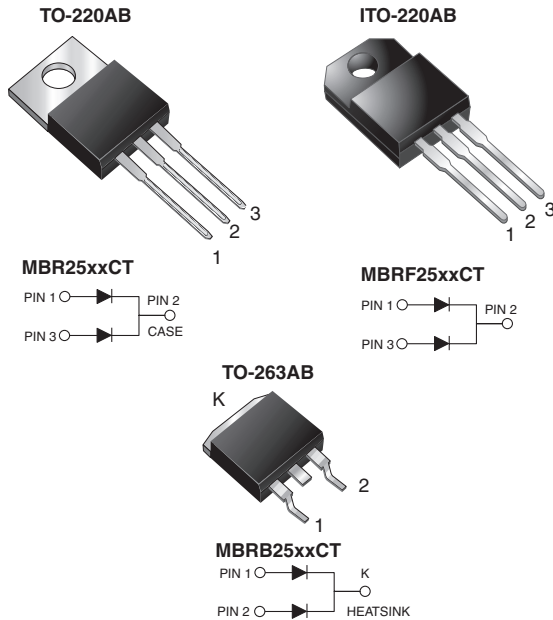


Dual Common-Cathode Schottky Rectifier



FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

| | |
|--------------------|--------------------------------|
| $I_{F(AV)}$ | 15 A x 2 |
| V_{RRM} | 35 V to 60 V |
| I_{FSM} | 150 A |
| V_F | 0.73 V at 30 A, 0.65 V at 15 A |
| $T_J \text{ max.}$ | 150 °C |

MAXIMUM RATINGS ($T_C = 25\text{ °C}$ unless otherwise noted)

| PARAMETER | SYMBOL | MBR2535CT | MBR2545CT | MBR2550CT | MBR2560CT | UNIT |
|--|-------------|-----------|-----------|-----------|-----------|------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 35 | 45 | 50 | 60 | V |
| Working peak reverse voltage | V_{RWM} | 35 | 45 | 50 | 60 | |
| Maximum DC blocking voltage | V_{DC} | 35 | 45 | 50 | 60 | |
| Maximum average forward rectified current total device at $T_C = 130\text{ °C}$ per diode | $I_{F(AV)}$ | 30 15 | | | | A |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I_{FSM} | 150 | | | | A |
| Peak repetitive reverse surge current per diode at $t_p = 2\ \mu\text{s}$, 1 kHz | I_{RRM} | 1.0 | | 0.5 | | |
| Peak non-repetitive reverse energy (8/20 μs waveform) per diode | E_{RSM} | 25 | | | | mJ |
| Electrostatic discharge capacitor voltage human body model: $C = 100\ \text{pF}$, $R = 1.5\ \text{k}\Omega$ | V_C | 25 | | | | kV |

MBR(F,B)2535CT thru MBR(F,B)2560CT

Vishay General Semiconductor



| MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | | |
|---|------------------|---------------|-----------|-----------|-----------|------|
| PARAMETER | SYMBOL | MBR2535CT | MBR2545CT | MBR2550CT | MBR2560CT | UNIT |
| Voltage rate of change (rated V _R) | dV/dt | 10 000 | | | | V/μs |
| Operating junction temperature range | T _J | - 65 to + 150 | | | | °C |
| Storage temperature range | T _{STG} | - 65 to + 175 | | | | |
| Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min | V _{AC} | 1500 | | | | V |

| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | | |
|--|-----------------------|---|----------------|-----------|-----------|-----------|------|
| PARAMETER | TEST CONDITIONS | SYMBOL | MBR2535CT | MBR2545CT | MBR2550CT | MBR2560CT | UNIT |
| Maximum instantaneous forward voltage per diode ⁽¹⁾ | I _F = 15 A | T _C = 25 °C | - | - | 0.75 | - | V |
| | I _F = 15 A | T _C = 125 °C | - | - | 0.65 | - | |
| | I _F = 30 A | T _C = 25 °C | 0.82 | - | - | - | |
| | I _F = 30 A | T _C = 125 °C | 0.73 | - | - | - | |
| Maximum instantaneous reverse current at blocking voltage per diode ⁽¹⁾ | | T _C = 25 °C T _C = 125 °C | I _R | 0.2 40 | 1.0 50 | | mA |

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | |
|---|------------------|-----|------|------|------|
| PARAMETER | SYMBOL | MBR | MBRF | MBRB | UNIT |
| Typical thermal resistance from junction to case per diode | R _{θJC} | 1.5 | 4.5 | 1.5 | °C/W |

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|---------------------------------|-----------------|--------------|---------------|---------------|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB | MBR2545CT-E3/45 | 1.85 | 45 | 50/tube | Tube |
| ITO-220AB | MBRF2545CT-E3/45 | 1.99 | 45 | 50/tube | Tube |
| TO-263AB | MBRB2545CT-E3/45 | 1.35 | 45 | 50/tube | Tube |
| TO-263AB | MBRB2545CT-E3/81 | 1.35 | 81 | 800/reel | Tape reel |
| TO-220AB | MBR2545CTHE3/45 ⁽¹⁾ | 1.85 | 45 | 50/tube | Tube |
| ITO-220AB | MBRF2545CTHE3/45 ⁽¹⁾ | 1.99 | 45 | 50/tube | Tube |
| TO-263AB | MBRB2545CTHE3/45 ⁽¹⁾ | 1.35 | 45 | 50/tube | Tube |
| TO-263AB | MBRB2545CTHE3/81 ⁽¹⁾ | 1.35 | 81 | 800/reel | Tape reel |

Note:

(1) Automotive grade AEC Q101 qualified



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

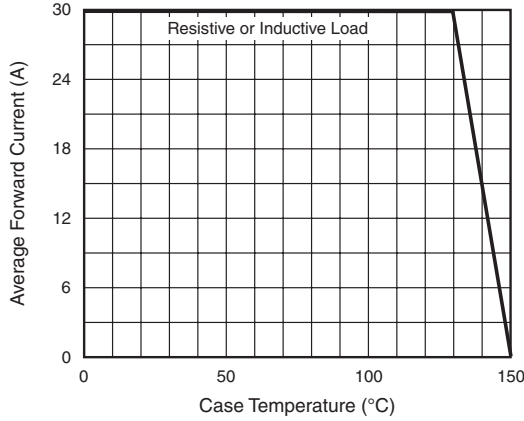


Figure 1. Forward Current Derating Curve

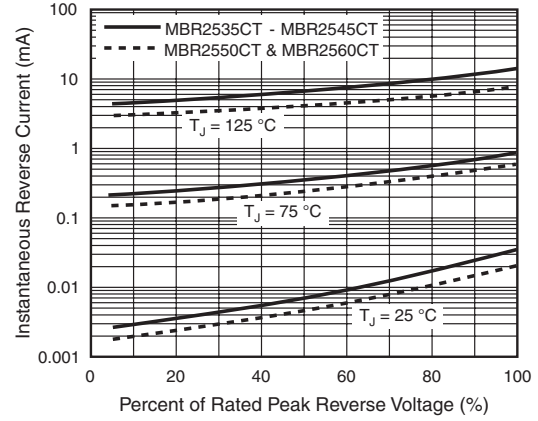


Figure 4. Typical Reverse Characteristics Per Diode

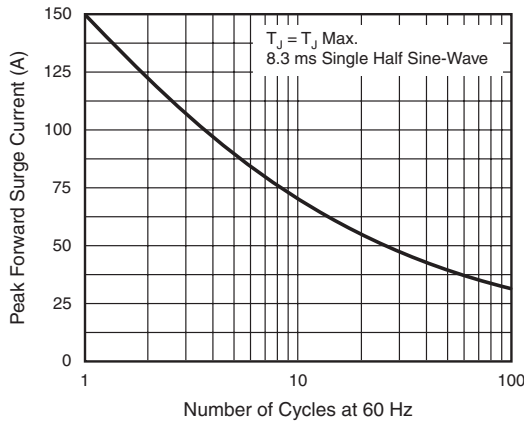


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

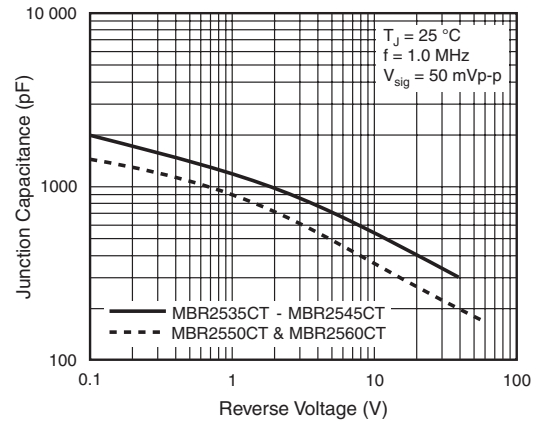


Figure 5. Typical Junction Capacitance Per Diode

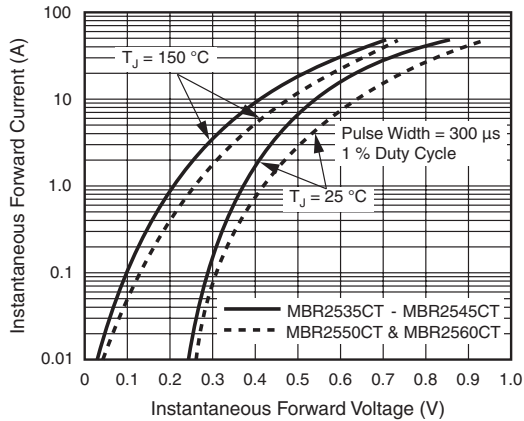


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

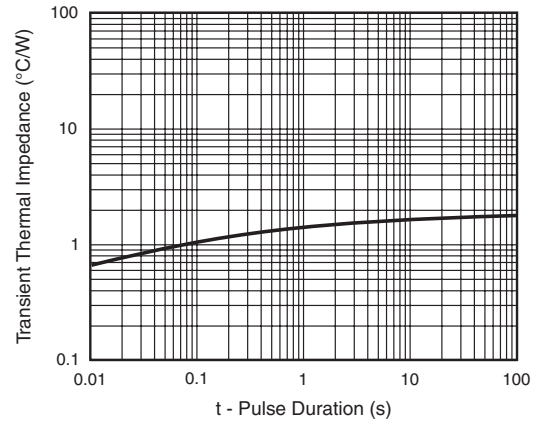


Figure 6. Typical Transient Thermal Impedance Per Diode

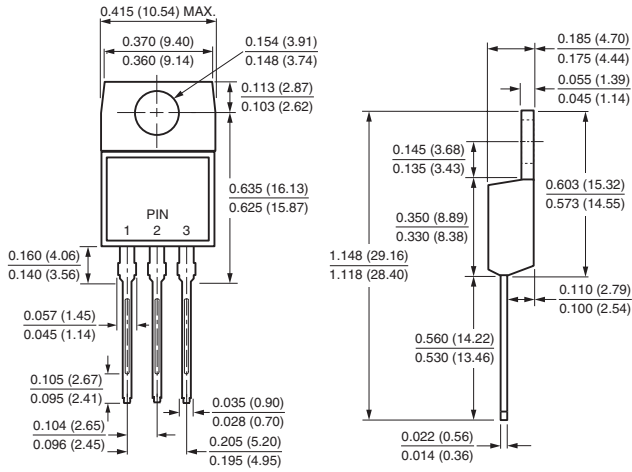
MBR(F,B)2535CT thru MBR(F,B)2560CT

Vishay General Semiconductor

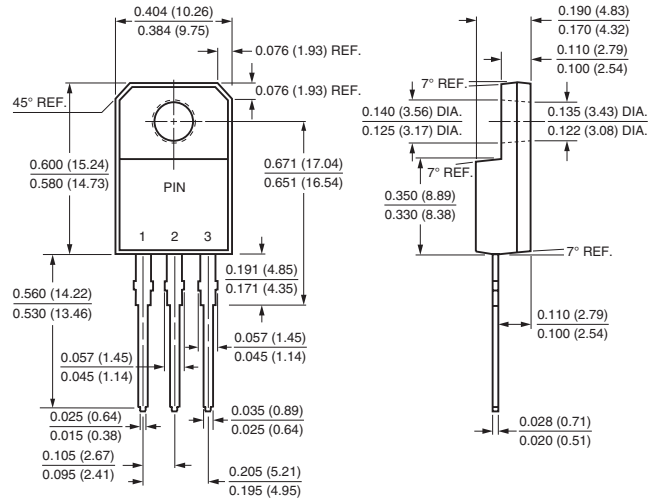


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

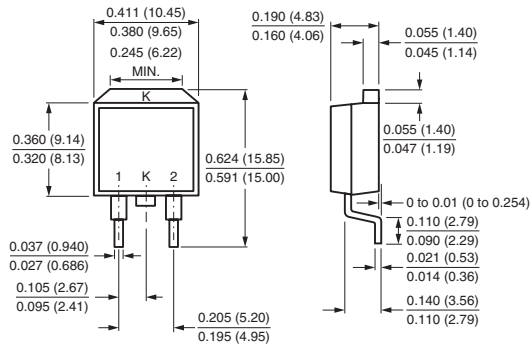
TO-220AB



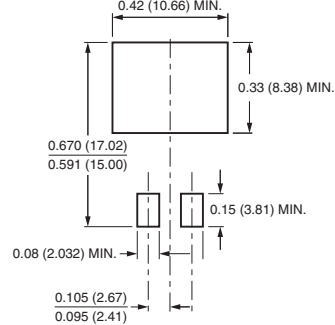
ITO-220AB



TO-263AB



Mounting Pad Layout





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All product specifications and data are subject to change without notice.

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